

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		80	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	80	Α	
D	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	82	mJ	
D	Power Dissipation		214	W	
P _D Derate Above 25 ^o C			1.43	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
R _{θJC}	Thermal Resistance, Junction to Case		0.7	°C/W	
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting T_J = 25°C, L = 40uH, I_{AS} = 64A, V_{DD} = 80V during inductor charging and V_{DD} = 0V during time in avalanche.

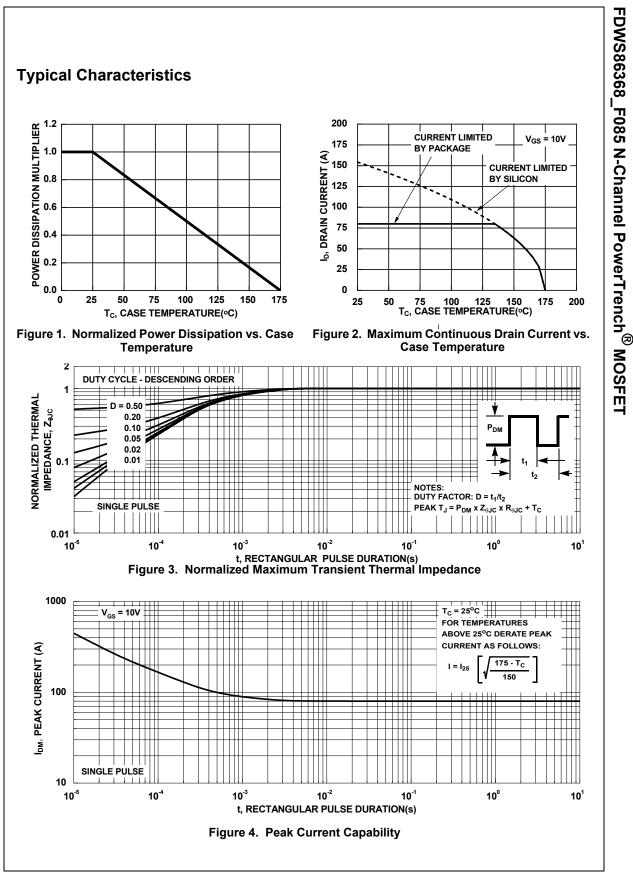
3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

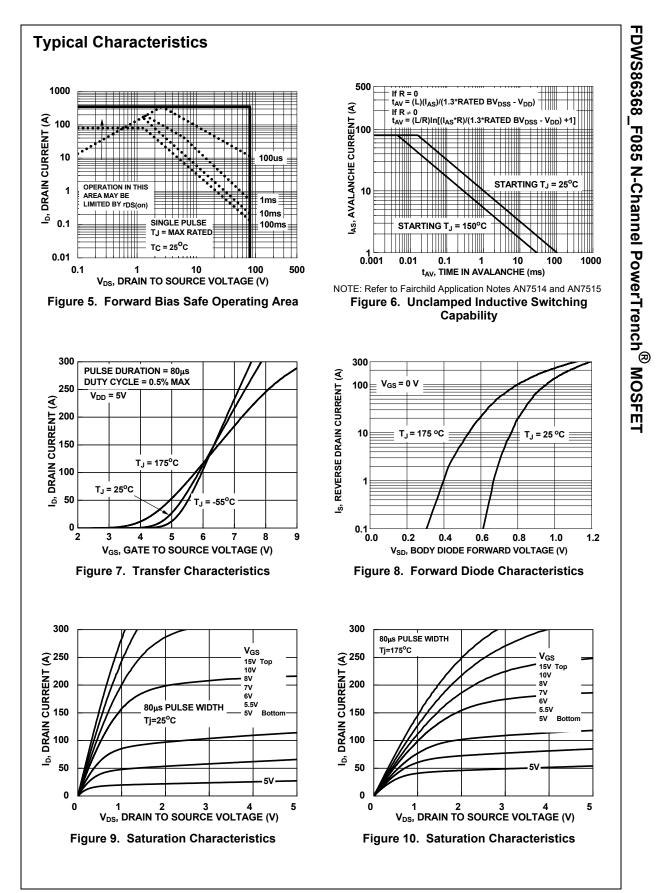
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDWS86368	FDWS86368_F085	Power56	13"	12mm	3000units

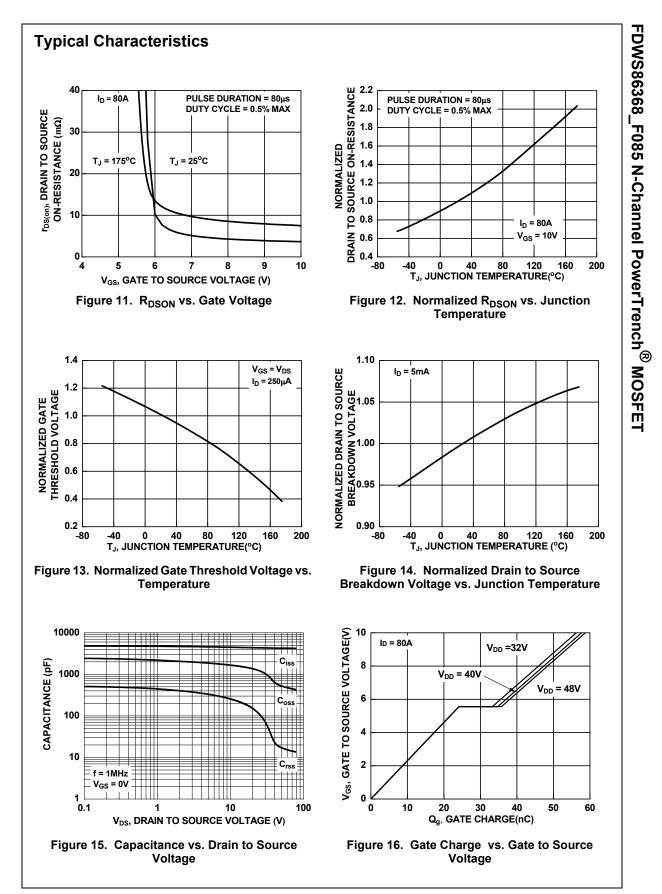
FDWS86368_F085 N-Channel PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics	,						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		80	-	_	V	
VD33		$V_{DS} = 80V$ $T_{J} = 25^{\circ}C$		-	-	1	μA	
I _{DSS}	Drain-to-Source Leakage Current			75°C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
	racteristics							1
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} ,	_D = 250	μA	2.0	3.0	4.0	V
		I _D = 80A,			-	3.7	4.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{J} = 1$	75 ^o C (Note 4)	-	7.4	9.0	mΩ
$\frac{C_{rss}}{R_g}}{Q_{g(ToT)}}$	Gate Resistance Total Gate Charge Threshold Gate Charge				2.5 57 8	- 75 -	Ω nC nC	
<u> </u>	Total Gate Charge			$\gamma = 64\gamma$	-	57	75	nC
		$V_{GS} = 0$ to 2	0 to 2V I _D = 80A		-	-	-	
Q _{gs}	Gate-to-Source Gate Charge			-	23	-	nC	
Q _{gd} Switchi	Gate-to-Drain "Miller" Charge				-	11	-	nC
on	Turn-On Time				_	-	60	ns
on t _{d(on)}	Turn-On Delay				-	23	-	ns
t _r	Rise Time	V _{DD} = 40V,	L _D = 804	۸.	-	22	-	ns
d(off)	Turn-Off Delay	$V_{GS} = 10V,$	R _{GEN} =	6Ω	-	32	-	ns
f	Fall Time				-	13	-	ns
t _{off}	Turn-Off Time			-	-	59	ns	
	ource Diode Characteristics	I _{SD} =80A, V			-	-	1.25	V
		I _{SD} = 40A, V			-	-	1.2	V
t _{rr}	Reverse-Recovery Time Reverse-Recovery Charge	I _F = 80A, dI	_{SD} /dt =	100A/μs	-	58	75	ns
Q _{rr}		$V_{DD} = 64V$			49	67	nC	

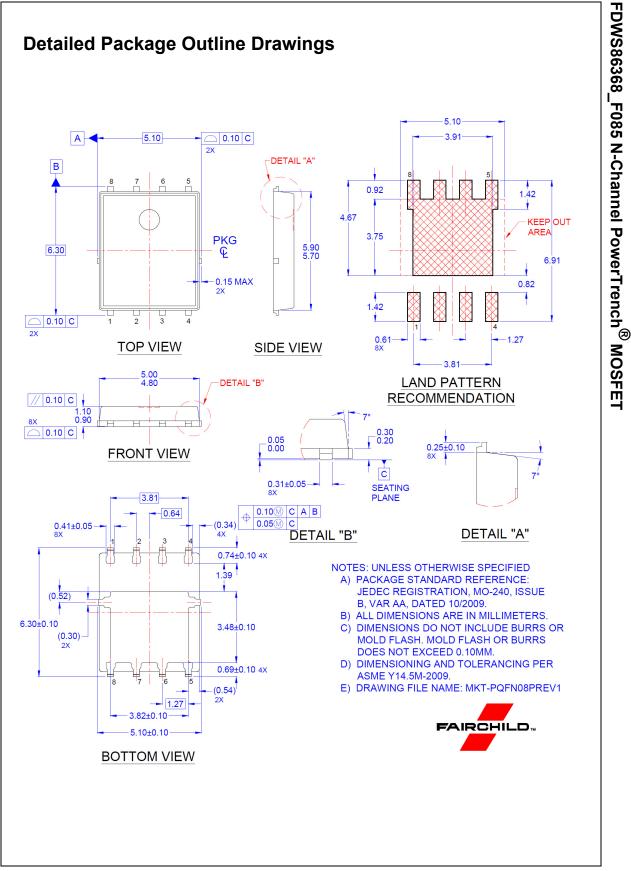


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